

■ **FEATURES**

- UL recognition, file #E230084
- Glass passivated chip junction
- Ideal for printed circuit boards
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

■ **TYPICAL APPLICATIONS**

General purpose use in AC/DC bridge full wave rectification for monitor, TV, printer, power supply, switching mode power supply, adapter, audio equipment, and home appliances applications.

■ **MECHANICAL DATA**

- **Package:** D3K  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■ **MAXIMUM RATINGS** ( $T_a=25^{\circ}\text{C}$  Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	D4UB05A	D4UB10A	D4UB20A	D4UB40A	D4UB60A	D4UB80A	D4UB100A
Device marking code			D4UB05A	D4UB10A	D4UB20A	D4UB40A	D4UB60A	D4UB80A	D4UB100A
Maximum Repetitive Peak Reverse Voltage	VRRM	V	50	100	200	400	600	800	1000
Maximum RMS Voltage	VRMS	V	35	70	140	280	420	560	700
Maximum DC blocking Voltage	VDC	V	50	100	200	400	600	800	1000
Average rectified output current @60Hz sine wave, R-load	With heatsink $T_c = 138^{\circ}\text{C}$	IO	A	4.0					
	Without heatsink $T_a = 25^{\circ}\text{C}$			1.3					
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, $T_j = 25^{\circ}\text{C}$	IFSM	A	135						
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, $T_j = 25^{\circ}\text{C}$			250						
Current squared time @1ms $\leq$ t $\leq$ 8.3ms $T_j = 25^{\circ}\text{C}$ , Rating of per diode	I <sup>2</sup> t	A <sup>2</sup> s	62.5						
Storage temperature	Tstg	°C	-55 ~ +150						
Junction temperature	Tj	°C	-55 ~ +150						
Dielectric strength @ Terminals to case, AC 1 minute	Vdis	KV	2						
Mounting torque @Recommend torque: 5kg·cm	Tor	kg·cm	8						

■ **ELECTRICAL CHARACTERISTICS** ( $T_a=25^{\circ}\text{C}$  Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	D4UB05A	D4UB10A	D4UB20A	D4UB40A	D4UB60A	D4UB80A	D4UB100A	
Maximum instantaneous forward voltage drop per diode	V <sub>F</sub>	V	I <sub>FM</sub> =2.0A							1.0	
Maximum DC reverse current at rated DC blocking voltage per diode	I <sub>R</sub>	μA	T <sub>j</sub> =25°C							5	
			T <sub>j</sub> =125°C							100	
Typical junction capacitance	C <sub>j</sub>	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C							40	

■ **THERMAL CHARACTERISTICS** ( $T_a=25^{\circ}\text{C}$  Unless otherwise specified)

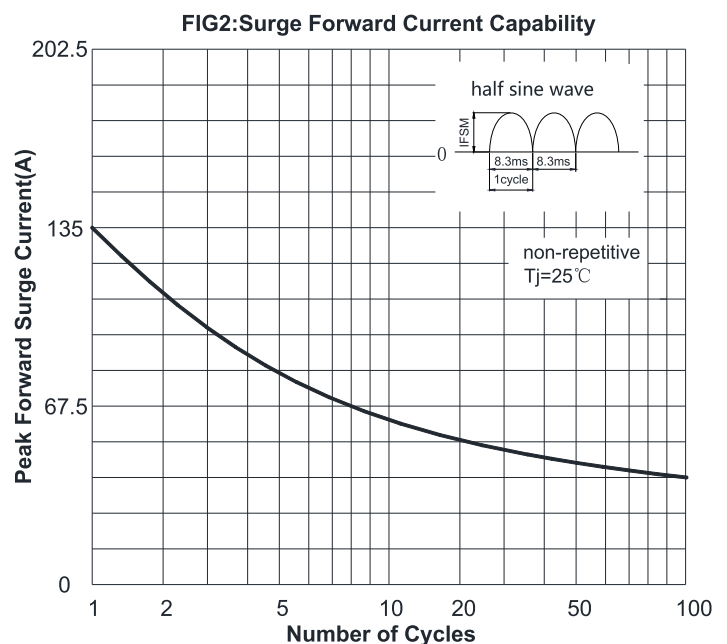
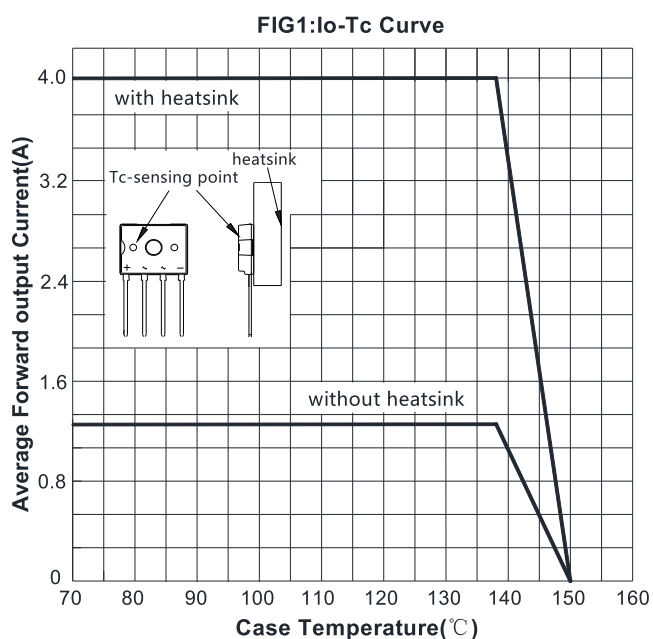
PARAMETER		SYMBOL	UNIT	D4UB05A	D4UB10A	D4UB20A	D4UB40A	D4UB60A	D4UB80A	D4UB100A	
Thermal resistance	Between junction and ambient, Without heatsink	R <sub>θJ-A</sub>	°C/W							55.0	
	Between junction and case, With heatsink	R <sub>θJ-C</sub>								1.5	

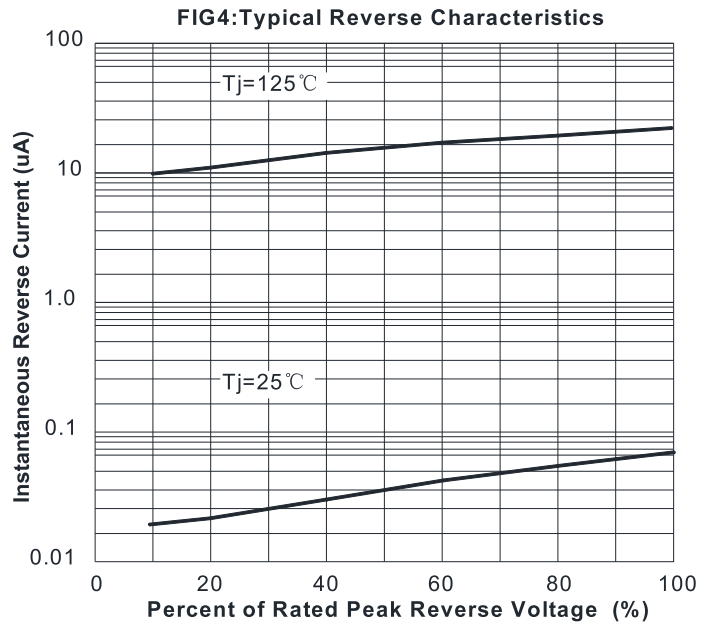
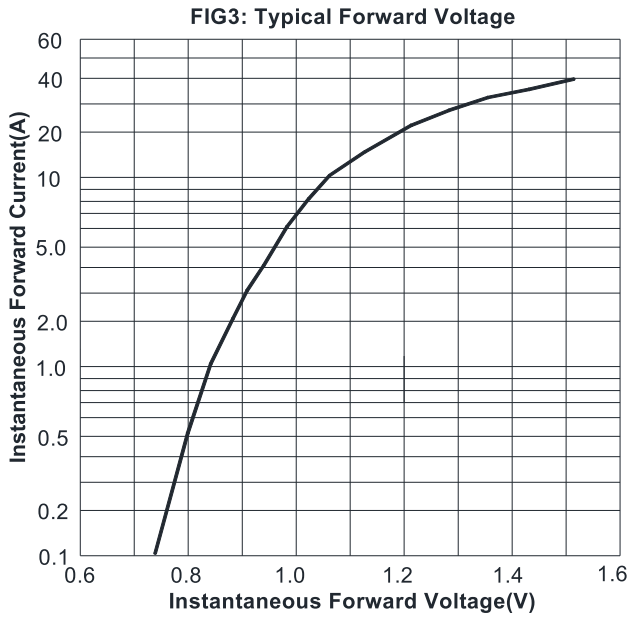
Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

■ **PACKAGING INFORMATION**

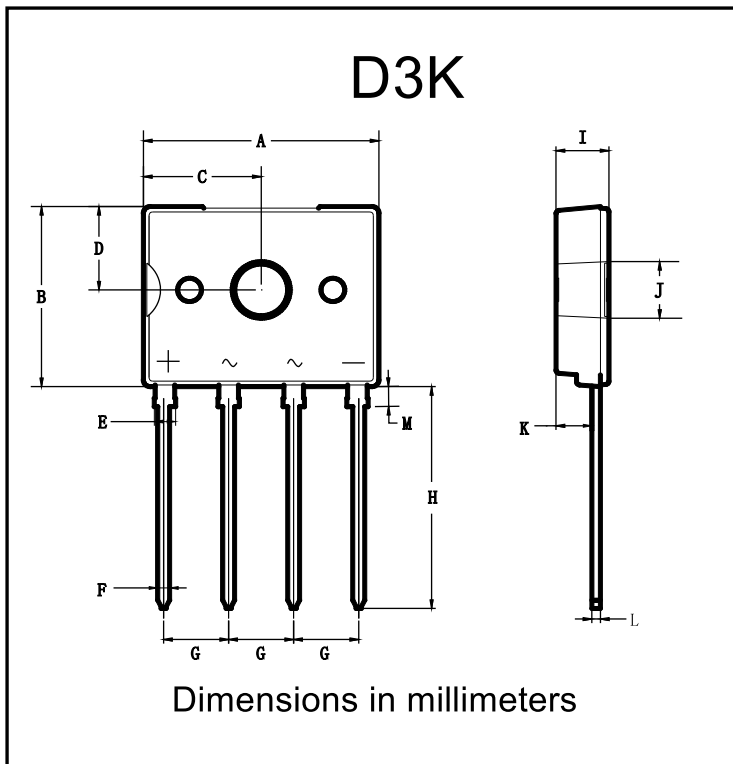
PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
D4UB05A -D4UB100A	B1	Approximate 1.266	25	1500	6000	TUBE

■ **CHARACTERISTICS (TYPICAL)**





■ **OUTLINE DIMENSIONS**



D3K		
Dim	Min	Max
A	13.30	14.30
B	10.30	11.30
C	6.40	7.40
D	4.50	5.50
E	1.05	1.45
F	0.60	0.85
G	3.70	3.90
H	13.10	13.50
I	2.60	3.60
J	3.10	3.40
K	2.00	2.20
L	0.40	0.60
M	0.90	1.50